

A Structure Electroluminescence on the Base of Diamond-like Films: a-C:H

A.A. Babaev^{C, S}

Institute of Physics, Dagestan Scientific Center of Russian Academy of Sciences, Makhachkala, Russia

I.K. Kamilov

Institute of Physics, Dagestan Scientific Center of Russian Academy of Sciences, Makhachkala,, Russia

A.M. Askhabov, S.B. Sultanov and S.B. Abdulvagabov

Institute of Physics, Dagestan Scientific Center of Russian Academy of Sciences, Makhachkala, Russia

An electroluminescence (EL) of the dark blue-light blue phosphorescence in an MOP structure with an active layer from diamond-like hydrogenized amorphous carbon (a-C:H) was observed. The quartz substrate is covered by the transparent ITO electrode, on which surface dielectric layers of Y_2O_3 and Al_2O_3 , radiate layer a-C:H and a second electrode Mo are located. The layers of different optic width of "the forbidden band" (E_{og}) a-C:H are obtained by a high-frequency (13.56 MHz) plasma-chemical gas-phase precipitating method from an argon-methane mixture (10% CH_4 90% Ar) at different conditions of the precipitation (correlation E/p , where E is electric field strength, p is gas mixture pressure in the camera) [1]. The thickness of layers is controlled by the laser interferometer during growth. Contacts and dielectric layers are covered by the method magnetron sputtering. EL is observed visually at voltages $U=120$ V and with frequency $f=6$ kHz. To excite a photoluminescence (PL), we use a nitric laser $\lambda=337.1$ nm. A registration of the radiating spectra is made in the photon calculation regime. The spectra of EL is studied at $U=150$ V and $f=6$ kHz. The EL spectrum is the broadband with the half-width $d=0.52$ eV and with the radiation maximum $E_m=2.51$ eV. For the PL, $E_{max}=2.91$ and $d=0.6$ eV. It should be noted that difference between maxima of EL and PL spectra is 0.4 eV independent of E_{og} of the active layer a-C:H. Probably, it indicates that recombination mechanisms are similar in both cases.

[1] A.A. Babaev, M.Sh. Abdulvagabov. Pisma v JTF. 15, 14, 75 (1989).